## NSN 5961-00-365-5965

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-365-5965 **Inclosure Material:** Plastic and metal **Overall Length:** Between 0.160 inches and 0.180 inches **Overall Diameter:** 0.367 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Thread Size:** 0.138 inches **Semiconductor Material:** Gallium arsenide Voltage Rating In Volts Per Characteristic: 3.0 reverse voltage, dc **Current Rating Per Characteristic:** 25.00 amperes source cutoff current absolute **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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